

Product data sheet

www.msksemi.com

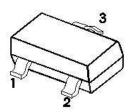


Semiconductor Co

Compiance

Features

- PD:225mW
- High Stability and High Reliability
- Low reverse leakage
 Mechanical Data
- PKG: SOT-23
- Epoxy UL: 94V-0
- Mounting Position: Any



SOT-23

BAW56-MS	BAV70-MS	BAV99-MS
10	1	10
2∘	2⊶→	2⊶
MARKING:A1	MARKING:A4	MARKING:A7
A1	A4	A7

Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

Symbol	Value	Unit
VR	70	V
Pd	225	mW
Tj	150	°C
Ts	-65-+150	°C
lo	200	mA
IFM	400	mA
IFSM	2.0	А
Reja	500	°C/W
	VR Pd Tj Ts IO IFM	VR 70 Pd 225 Tj 150 Ts -65-+150 IO 200 IFM 400

Valid provided that electrodes are kept at ambient temperature.

Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified).

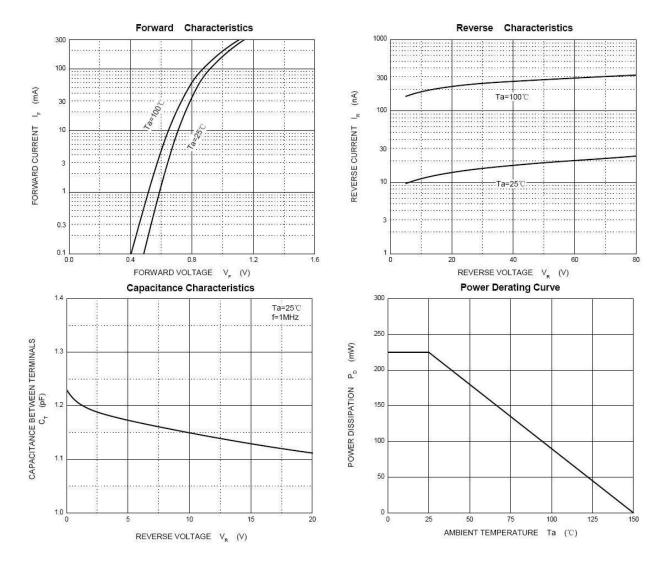
Symbols			Limits		
	Parameter	Test Condition	Min	Max	Unit
VRB	Reverse Voltage	IB=100uA	70		V
IR	Reverse Leakage Current	VR=70V		2.5	uA
		IF=1mA		0.715	
VF	Forward Voltage	IF=10mA		0.855	V
		IF=50mA		1.00	
		IF=150mA		1.25	
TRR	Reverse Recovery Time	IF= IR=10mA,RL=100Ω IRR=0.1xIR	· · · · · · · · · · · · · · · · · · ·		nS
Ст	Capacitance	VR=0V, f=1MHZ 1.5		pF	



BAW56-MS/BAV70-MS/BAV99-MS HF 🐼

Semiconductor

Compiance

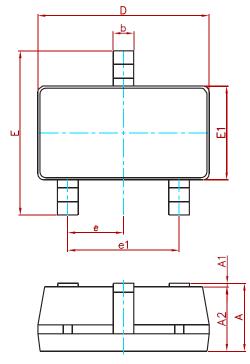


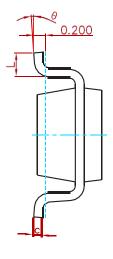
Typical Characteristics



Semiconductor Compiance

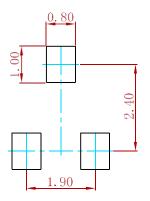
PACKAGE MECHANICAL DATA





Symbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
0	0°	8°	0°	8°

Suggested Pad Layout



Note: 1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.

3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
BAW56-MS/BAV70-MS/BAV99-MS	SOT-23	3000



Semiconductor Compiance

Attention

■ Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.

MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications f any andall MSKSEMI Semiconductor products described orcontained herein.

■ Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

■ MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuits for safedesign, redundant design, and structural design.

■ In the event that any or all MSKSEMI Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.

■ No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.

■ Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

 Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. Whendesigning equipment, refer to the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by MSKSEMI manufacturer:

Other Similar products are found below :

MMBD3004S-13-F RD0306T-H BAV17-TR BAV19-TR HSC285TRF-E 1N3611 NTE156A NTE574 NTE6244 1SS181-TP 1SS193,LF 1SS400CST2RA SDAA13 SHN2D02FUTW1T1G LS4151GS08 1N4449 1N456A 1N4934-E3/73 1N914B 1N914BTR 1SS226-TP RFUH20TB3S D291S45T BAV300-TR BAW56DWQ-7-F BAW75-TAP MM230L-CAA IDW40E65D1 JAN1N3600 LL4151-GS18 053684A SMMSD4148T3G 707803H NSVDAN222T1G CDSZC01100-HF LL4150-M-08 1N4454-TR BAV199E6433HTMA1 BAS28-7 BAW56HDW-13 BAS28 TR VS-HFA04SD60STR-M3 NSVM1MA152WKT1G RGP30D-E3/73 BAV99TQ-13-F BAS21DWA-7 BAV99HDW-13 NTE6250 NTE582-4 NTE582-6